# NSN 5962-01-293-7703

Memory Microcircuit - Page 1 of 1



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## **Body Length:**

Between 0.935 inches and 0.970 inches

## Body Width:

Between 0.290 inches and 0.320 inches

## **Body Height:**

Between 0.080 inches and 0.205 inches

## **Operating Tempurature Range:**

+0.0/+75.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## **Features Provided:**

Hermetically sealed and programmable and positive outputs and electrostatic sensitive

#### **Inclosure Material:**

Ceramic

#### Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Transistor-transistor logic

# Input Circuit Pattern:

14 input

# **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

## Time Rating Per Chacteristic:

40.00 nanoseconds propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Pal

## **Terminal Type And Quantity:**

20 printed circuit

## Shelf Life:

N/a

#### Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

## Fiig:

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